2015

NEW

Part II 3-Tier ELECTRONICS

PAPER---II

(General)

Full Marks: 90

Time: 3 Hours

The figures in the right-hand margin indicate full marks.

Candidates are required to give their answers in their own words as far as practicable.

Illustrate the answers wherever necessary.

Group-A

Answer any two questions.

15×2

- 1. (a) Implement X-OR gate using :
 - (i) NAND; (ii) NOR gate.
 - (b) Describe the operating principle of a CMOS 'NOR' gate.
 - (c) Minimize the following functions using Karnaugh Map methods:
 - (i) $f_1 = \Sigma m$ (0, 2, 4, 6, 7, 8, 10, 12, 13, 15)
 - (ii) $f_2 = \prod M (5, 6, 7, 9, 10, 11, 13, 14, 15)$

(2+2)+3+(4+4)

- 2. (a) Design an even parity Bit generator for 4-bit inputs.
 - (b) Use a 4×1 MUX to implement the logic function: $F(A, B, C) = \Sigma m(1, 2, 4, 7)$.
 - (c) Design a synchronous 3-bit up counter using J-K F/F & draw its circuit diagram.
 - (d) What is the difference between Static RAM & Dynamic RAM? 4+4+4+3
- 3. (a) With a neat sketch draw Cathode Ray tube and describe its each components.
 - (b) Write short note on Maxwell bridge.
 - (c) With proper circuit diagram describe the square wave generator. 5+5+5

Group-B

Answer any five questions:

8×5

- 4. (a) Convert the following numbers to decimal numbers:
 (i) (4057.06)₈; (ii) (11011.101)₂; (iii) 5C7₁₆.
 - (b) Realize the AND gate using diode logic only.
 - (c) Convert the following into the gray number: 3A7₁₆
 - (d) What is De Morgan's theorem?

3+2+2+1

- 5. (a) What is the advantage & disadvantage of CMOS?
 - (b) Write short notes on :
 - (i) Propagation delay; (ii) Noise Margin.

 $3+(2\frac{1}{2}+2\frac{1}{2})$

- 6. (a) Draw a circuit diagram of Master-Slave F | F & explain its principle of operation.
 - (b) What is the difference between synchronous counter & asynchronous counter? 5+3
- 7. (a) What are the components in a standard power supply unit?
 - (b) Discuss the principle of operation of a voltage regulator using transistor.
 - (c) What do you mean by percentage regulation of a voltage regulator? 2+4+2
- 8. Give the structure and design method of a multi-range DC Voltmeter having 0 10V, 0 50V & 0 250V ranges. Assume the internal resistance of the basic meter is 100Ω & full scale current is 1mA.
- 9. (a) Describe the function generator circuit using block diagram.
 - (b) What is the difference between dual beam CRO and dual trace CRO? 5+3
 - 10. (a) Write short note on Q-meter.
 - (b) How can a wave form be displayed in a CRO?
 - 11. (a) What is the basic difference between ammeter and voltmeter?
 - (b) Explain with a block diagram of the electronic counter in the Frequency Mode of operation. 2+6

Group-C

Answer any five questions:

 4×5

12. Prove that :

2+2

- (i) $AB + \overline{A}C + BC = AB + \overline{A}C$
- (ii) $(A + B)(\overline{A} + C)(B + C) = (A + B) + (\overline{A} + C)$.
- Draw the logic diagram of a 4-bit directional shift register.

14. Design a variable half-wave rectifier circuit using an SCR.

- 15. Design a 4-bit comparator circuit. 4
- 16. Implement the following Boolean function using an 8:1 multiplexer considering D as the input and A, B and C as the selection lines:
 F(A, B, C, D) = Σm(0, 2, 3, 5, 8, 9, 10, 11)

17. Realize two outputs F₁ & F₂ using a 4×2 PROM: 4

$$F_1(A_1, A_0) = \Sigma m(0, 2)$$

$$F_2(A_1, A_0) = \Sigma m(0, 1, 3)$$

- Describe the function of Horizontal and Vertical deflection systems in CRO.
- 19. What is the function of attenutor & vertical amplifier in case of CRO?

*